



The graphic consists of several overlapping squares in various colors: orange, green, blue, purple, and red. They are arranged to form a stylized letter 'C' shape, with some squares pointing left and others pointing right.

# Photocoupler Product Data Sheet

## 4N35/ 4N37 (M, S, S-TA1)

Spec No. :DS-70-99-0012

Effective Date: 08/22/2017

Revision: E

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

### 1. DESCRIPTION

#### 1.1 Features

- Current transfer ratio (CTR : MIN. 100% at  $I_F = 10\text{mA}$ ,  $V_{CE} = 10\text{V}$ ,  $T_a=25^\circ\text{C}$ )
- High input-output isolation voltage  
4N35 series :  $V_{iso} = 3,550\text{Vrms}$   
4N37 series :  $V_{iso} = 1,500\text{Vrms}$
- Response time ( $t_r$  : TYP.  $3\mu\text{s}$  at  $V_{cc} = 10\text{V}$ ,  $I_C = 2\text{mA}$ ,  $R_L = 100\Omega$ )
- Dual-in-line package :  
4N35, 4N37
- Wide lead spacing package :  
4N35M, 4N37M
- Surface mounting package :  
4N35S, 4N37S
- Tape and reel packaging :  
4N35S-TA, 4N37S-TA, 4N35S-TA1, 4N37S-TA1
- Safety approval
  - \* UL approved (No. E113898)
  - \* CSA approved (No. CA91533-1)
  - \* FIMKO approved ( No. 193422-01)
  - \* VDE approved ( No. 40015248)
  - \* BSI approved (No. 9018-9)
  - \* CQC approved (No.CQC11001061921-2)
- Creepage distance > 8.0 mm ; Clearance > 8.0 mm
- The relevant models are the models Approved by VDE according to DIN EN 60747-5-5

Approved Model No.: 4N35-V / 4N37-V / 4N35M-V / 4N37M-V / 4N35S-V / 4N37S-V / 4N35STA-V / 4N37STA-V /  
4N35STA1-V / 4N37STA1-V

VDE approved No.: 40015248 (According to the specification DIN EN 60747-5-5)

- Operating isolation voltage VIORM : 420V (Peak)
- Transient voltage VTR : 6000V (Peak)
- Pollution : 2 (According to VDE 0110-1 : 1997-04)
- Clearances distance (Between input and output) : 7.0mm (MIN.)
- Creepage distance (Between input and output) : 7.0mm (MIN.)
- Isolation thickness between input and output : 0.4mm (MIN.)
- Safety limit values Current ( $I_{si}$ ) : 400mA (Diode side)

Power ( $P_{si}$ ) : 700mW (Phototransistor side)

Temperature( $T_{si}$ ) : 175°C

In order to keep safety electric isolation of photocoupler, please set the protective circuit to keep within safety limit values when the actual application equipment troubled.

- Indication of VDE approval prints "VDE" on sleeve package.

## Photocoupler 4N3X series

- RoHS Compliance  
All materials be used in device are followed EU RoHS directive (No.2002/95/EC).
- ESD pass HBM 8000V/MM2000V
- MSL class1

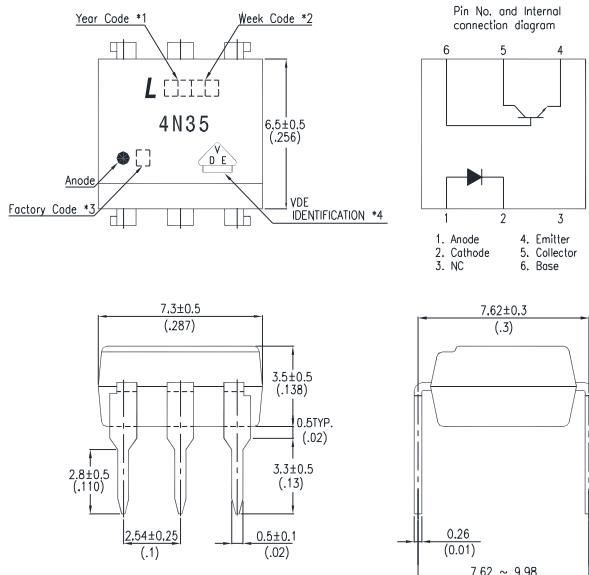
### 1.2 Applications

- Power Supply regulators
- Digital logic inputs
- Microprocessor inputs

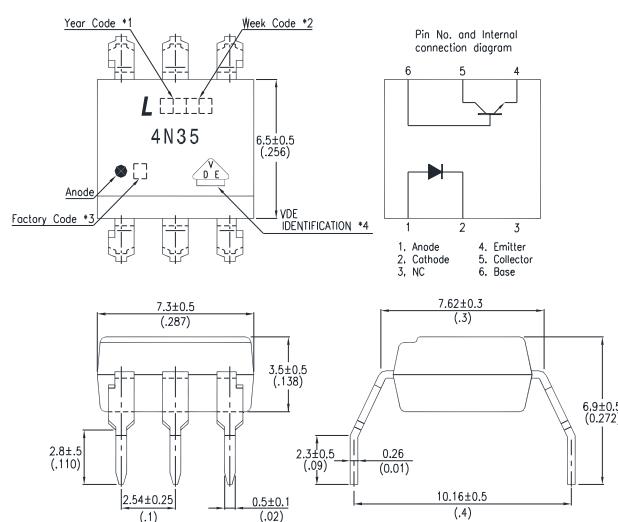
## Photocoupler 4N3X series

### 2. PACKAGE DIMENSIONS

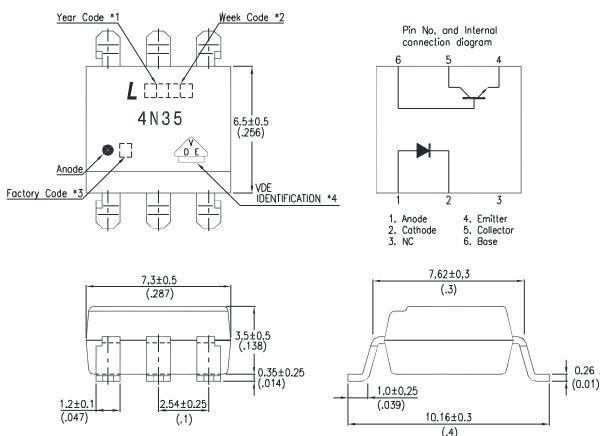
#### 2.1 4N35



#### 2.2 4N35M



#### 2.3 4N35S



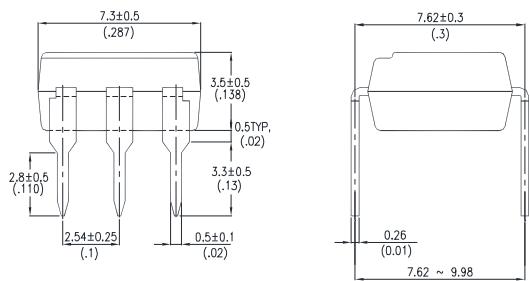
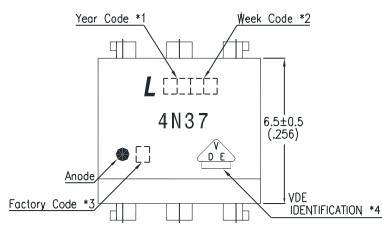
#### Notes :

1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (W: China-CZ, Y: Thailand X: China-TJ).
4. VDE option.

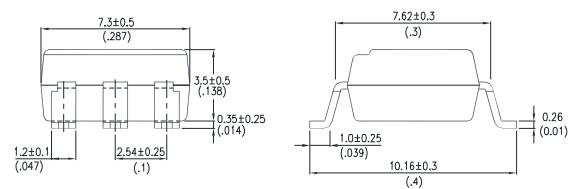
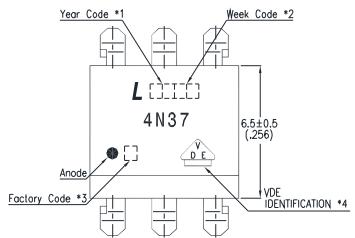
Dimensions in millimeters(inches).

## Photocoupler 4N3X series

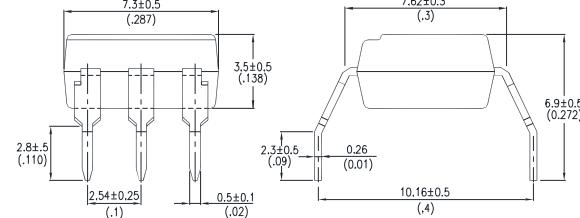
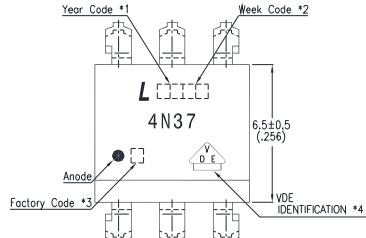
### 2.4 4N37



### 2.6 4N37S



### 2.5 4N37M



#### Notes :

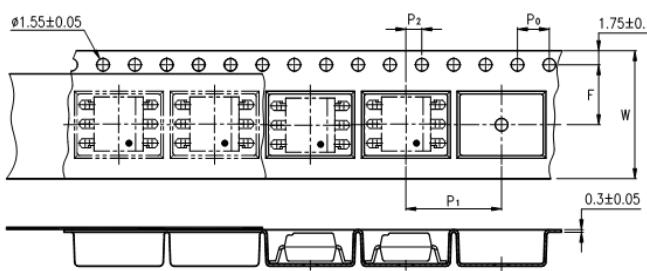
1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (W: China-CZ, Y: Thailand X: China-TJ).
4. VDE option.

Dimensions in millimeters(inches).

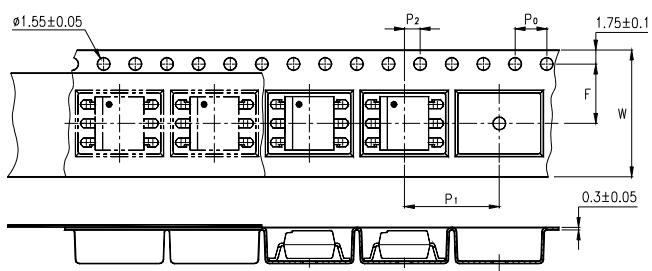
## Photocoupler 4N3X series

### 3. TAPING DIMENSIONS

3.1 4N35S-TA , 4N37S-TA :



3.2 4N35S-TA1 , 4N37S-TA1 :



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (0.63)
Pitch of sprocket holes	P <sub>0</sub>	4±0.1 (0.15)
Distance of compartment	F	7.5±0.1 (0.295)
	P <sub>2</sub>	2±0.1 (0.079)
Distance of compartment to compartment	P <sub>1</sub>	12±0.1 (0.472)

### 3.3 Quantities Per Reel

Package Type	TA/TA1
Quantities (pcs)	1000

Photocoupler  
 4N3X series

## 4. RATING AND CHARACTERISTICS

## 4.1 Absolute Maximum Ratings at Ta=25°C

Parameter		Symbol	Rating	Unit
Input	Forward Current	I <sub>F</sub>	60	mA
	Reverse Voltage	V <sub>R</sub>	6	V
	Power Dissipation	P	100	mW
Output	Collector - Emitter Voltage	V <sub>CEO</sub>	30	V
	Emitter - Collector Voltage	V <sub>ECO</sub>	7	V
	Collector - Base Voltage	V <sub>CBO</sub>	70	V
	Collector Current	I <sub>C</sub>	100	mA
	Collector Power Dissipation	P <sub>C</sub>	300	mW
Total Power Dissipation		P <sub>tot</sub>	350	mW
*1 Isolation Voltage	4N35 series	V <sub>iso</sub>	3,550	V <sub>rms</sub>
	4N37 series		1,500	V <sub>rms</sub>
Operating Temperature		T <sub>opr</sub>	-55 ~ +100	°C
Storage Temperature		T <sub>stg</sub>	-55 ~ +150	°C
*2 Soldering Temperature		T <sub>sol</sub>	260	°C

\*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

(1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.

(2) The isolation voltage tester with zero-cross circuit shall be used.

(3) The waveform of applied voltage shall be a sine wave.

\*2. For 10 Seconds

Photocoupler  
 4N3X series

## 4.2 ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

PARAMETER			SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage		VF	—	1.2	1.5	V	IF=10mA
	Reverse Current		IR	—	—	10	μA	VR=4V
	Terminal Capacitance		Ct	—	50	—	pF	V=0, f=1KHz
OUTPUT	Collector Dark Current	Ta=25°C	ICEO	—	—	50	nA	VCE=10V, IF=0
	Current	Ta=100°C		—	—	500	μA	VCE=30V, IF=0
	Collector-Emitter Breakdown Voltage		BVCEO	30	—	—	V	IC=0.1mA IF=0
	Emitter-Collector Breakdown Voltage		BVECO	7	—	—	V	IE=10μA IF=0
	Collector-Base Breakdown Voltage		BVCBO	70	—	—	V	IC=0.1mA IF=0
	Collector Current		IC	10	—	—	mA	IF=10mA
TRANSFER CHARACTERISTICS	*Current Transfer Ratio		CTR	100	—	—	%	VCE=10V
	Collector-Emitter Saturation Voltage		VCE(sat)	—	—	0.3	V	IF=50mA IC=2mA
	Isolation Resistance		Riso	5×10 <sup>10</sup>	1×10 <sup>11</sup>	—	Ω	DC500V 40 ~ 60% R.H.
	Floating Capacitance		Cf	—	1	2.5	pF	V=0, f=1MHz
	Response Time (Rise)		tr	—	3	10	μs	VCE=10V, IC=2mA
	Response Time (Fall)		tf	—	3	10	μs	RL=100Ω

$$*CTR = \frac{I_C}{I_F} \times 100\%$$

Photocoupler  
 4N3X series

## 4.3 ISOLATION SPECIFICATION ACCORDING TO VDE

Parameter		Symbol	Conditions	Rating	Unit	Remark
Class of environmental test		-	DIN IEC68	55/100/21	-	
Pollution		-	DIN VDE0110	2	-	
Maximum Operating Isolation Voltage		$V_{IORM}$	-	420	$V_{PEAK}$	Refer to the Diagram 1, 2
Partial Discharge Test Voltage (Between Input and Output)	Diagram 1	$V_{pr}$	$tp=60s, qc<5pC$	630	$V_{PEAK}$	
	Diagram 2		$tp=1s, qc<5pC$	788	$V_{PEAK}$	
Maximum Over-Voltage		$V_{INITIAL}$	$t_{INI} = 10s$	6000	$V_{PEAK}$	
Safety Maximum Ratings						
1) Case Temperature		$T_{si}$	$I_F = 0, P_c = 0$	175	°C	Refer to the Figure 1, 3
2) Input Current		$I_{si}$	$P_c=0$	400	mA	
3) Electric Power (Output or Total Power Issipation)		$P_{si}$	-	700	mW	
Isolation Resistance (Test Voltage Between Input and Output : DC500V)		$R_{ISO}$	$T_a=T_{si}$	MIN. $10^9$	$\Omega$	
			$T_a=Topr(MAX.)$	MIN. $10^{11}$		
			$T_a=25\text{ }^\circ\text{C}$	MIN. $10^{12}$		

Precautions in performing isolation test

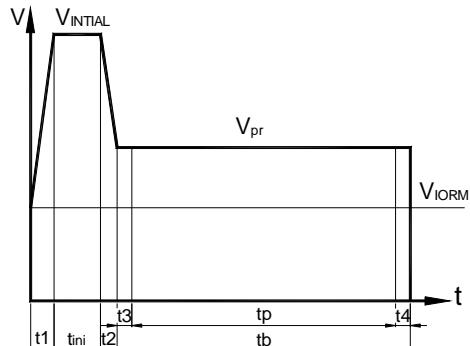
\* Partial discharge test methods shall be the ones according to the specifications of DIN EN 60747-5-5

\* Please don't carry out isolation test ( $V_{iso}$ ) over  $V_{INITIAL}$ , This product deteriorates isolation characteristics by partial discharge due to applying high voltage (ex.  $V_{INITIAL}$ ). And there is possibility that this product occurs partial discharge in operating isolation voltage ( $V_{IORM}$ )

## Photocoupler 4N3X series

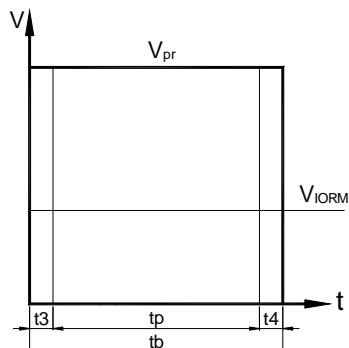
### 4.4 PARTIAL DISCHARGE TEST METHOD

Method (A) for type testing and random testing.



$t_1, t_2$	= 1 to 10s
$t_3, t_4$	= 1s
$t_p$ (Partial Discharge Measuring Time)	= 60s
$t_b$	= 62s
$t_{ini}$	= 10s

Method (B) for routine testing.



$t_3, t_4$	= 0.1s
$t_p$ (Partial Discharge Measuring Time)	= 1s
$t_b$	= 1.2s

The partial discharge level shall not exceed 5 pc during the partial discharge measuring time interval  $t_p$  under the test conditions shown above.

## Photocoupler 4N3X series

### 5. CHARACTERISTICS CURVES

Fig.1 Forward Current vs. Ambient Temperature

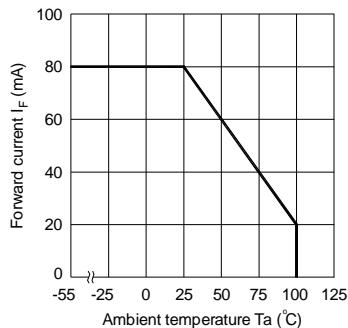


Fig.2 Collector Power Dissipation vs. Ambient Temperature

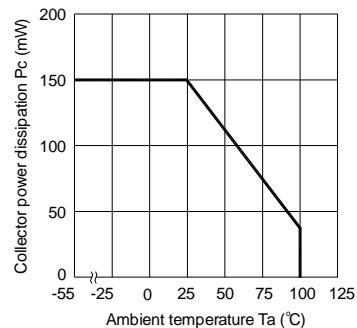


Fig.3 Forward Current vs. Forward Voltage

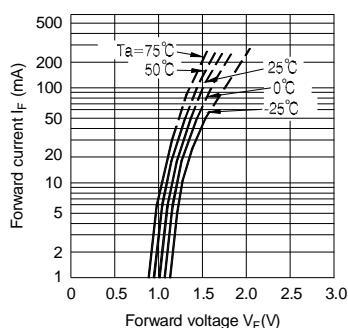


Fig.4 Current Transfer Ratio vs. Forward Current

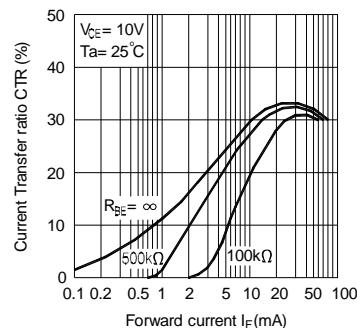


Fig.5 Collector Current vs. Collector-emitter Voltage

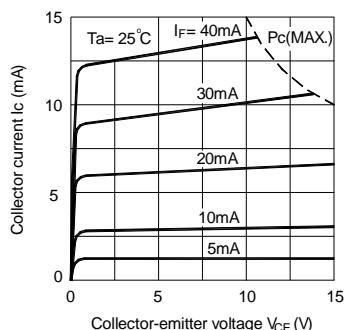
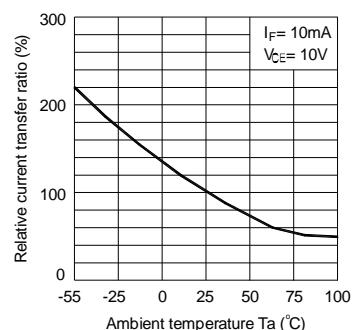


Fig.6 Relative Current Transfer Ratio vs. Ambient Temperature



## Photocoupler 4N3X series

Fig.7 Collector-emitter Saturation Voltage vs.  
Ambient Temperature

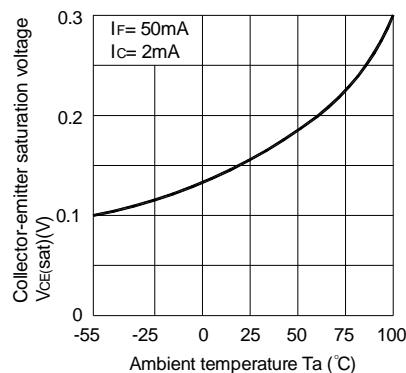


Fig.8 Collector Dark Current vs.  
Ambient Temperature

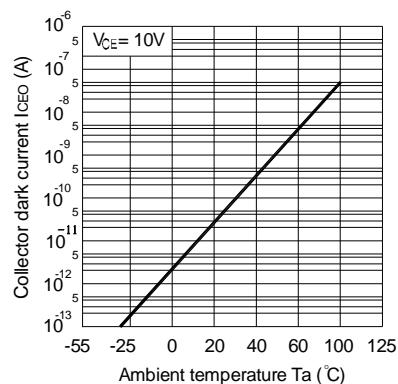


Fig.9 Response Time vs. Load Resistance

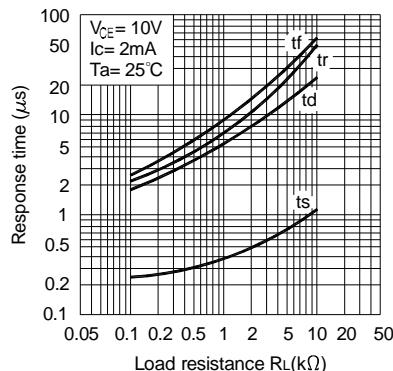


Fig.10 Frequency Response

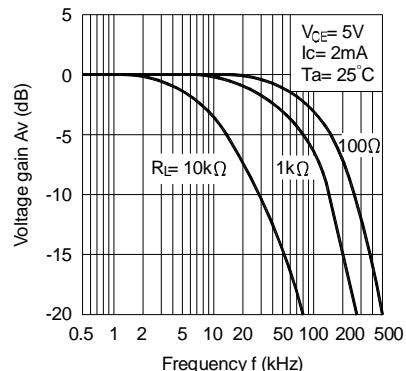
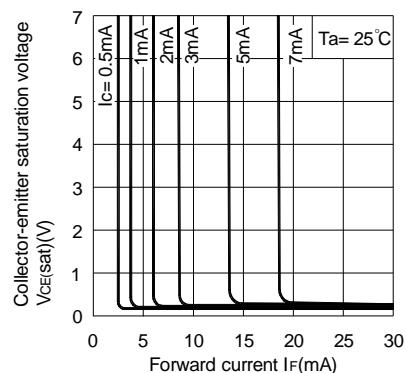
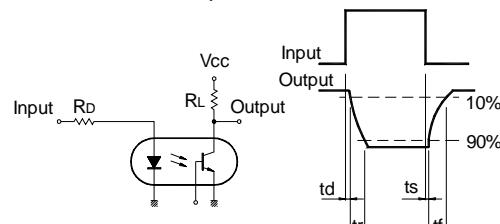


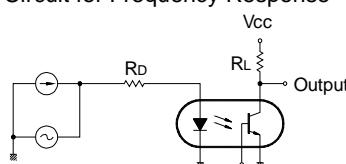
Fig.11 Collector-emitter Saturation  
Voltage vs. Forward Current



Test Circuit for Response Time



Test Circuit for Frequency Response



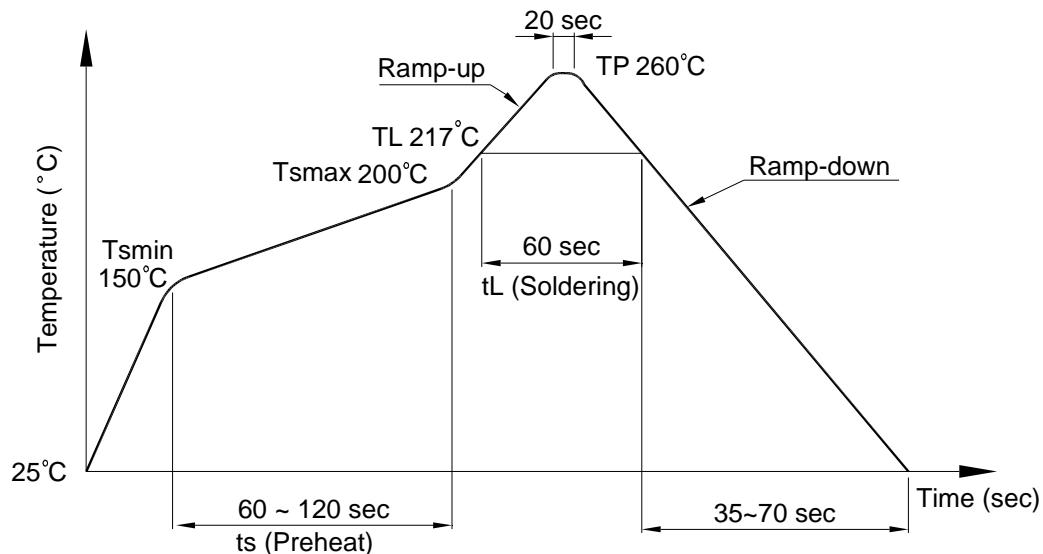
## Photocoupler 4N3X series

### 6. TEMPERATURE PROFILE OF SOLDERING

#### 6.1 IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

Profile item	Conditions
Preheat	
- Temperature Min ( $T_{Smin}$ )	150°C
- Temperature Max ( $T_{Smax}$ )	200°C
- Time (min to max) ( $t_s$ )	90±30 sec
Soldering zone	
- Temperature ( $T_L$ )	217°C
- Time ( $t_L$ )	60 sec
Peak Temperature ( $T_P$ )	260°C
Ramp-up rate	3°C / sec max.
Ramp-down rate	3~6°C / sec



## Photocoupler 4N3X series

### 6.2 Wave soldering (JEDEC22A111 compliant)

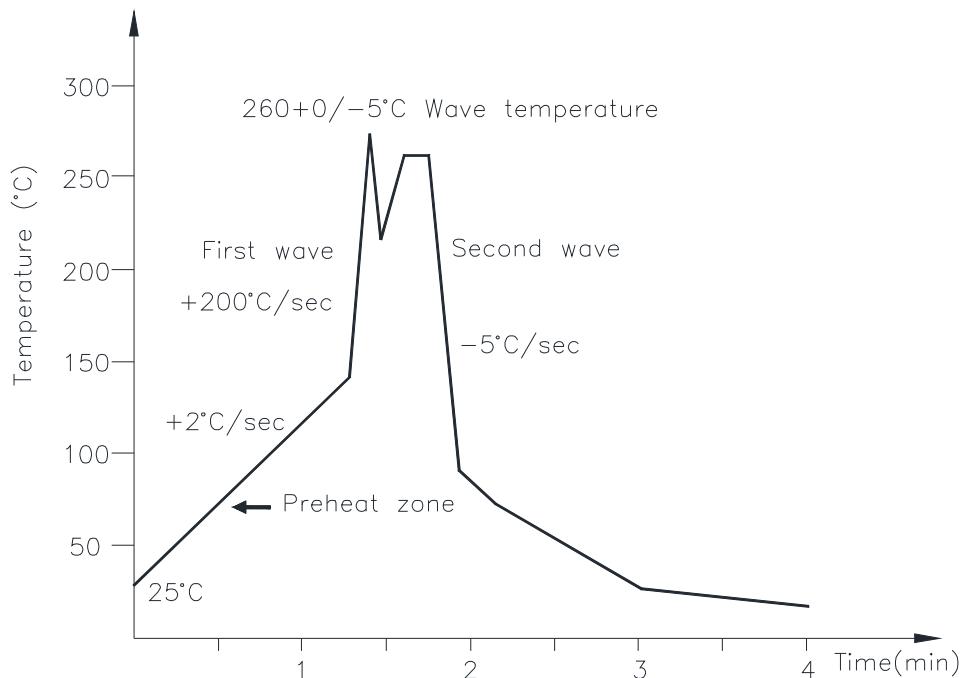
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C

Time: 10 sec.

Preheat temperature: 25 to 140°C

Preheat time: 30 to 80 sec.



### 6.3 Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

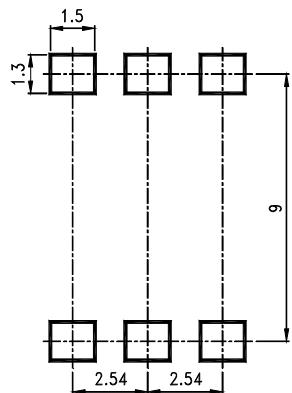
Temperature: 380+0/-5°C

Time: 3 sec max.

**Photocoupler  
4N3X series**

**7. RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)**

Unit: mm



## 8. Naming rule

**4N3X (1)-(2)**

DEVICE PART NUMBER

(1) No suffix = Dual-in-Line package

M = Wide lead spacing package

S = Surface mounting package

(2) TAPING TYPE (TA,TA1 or none)

4N3X series have tape and reel solution.

Please refer to orientation of taping on Page P5

Example : 4N35S-TA1

**4N3X(1)(2)-V**

DEVICE PART NUMBER

(1) No suffix = Dual-in-Line package

M = Wide lead spacing package

S = Surface mounting package

(2) TAPING TYPE (TA,TA1 or none)

4N3X series have tape and reel solution.

Please refer to orientation of taping on Page P5

(3) VDE order option

Example : 4N35STA1-V-G

## 9. Notes:

- LiteOn is continually improving the quality, reliability, function or design and LiteOn reserves the right to make changes without further notices.
- The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- When requiring a device for any "specific" application, please contact our sales in advice.
- If there are any questions about the contents of this publication, please contact us at your convenience.
- The contents described herein are subject to change without prior notice.
- Immerge unit's body in solder paste is not recommended.